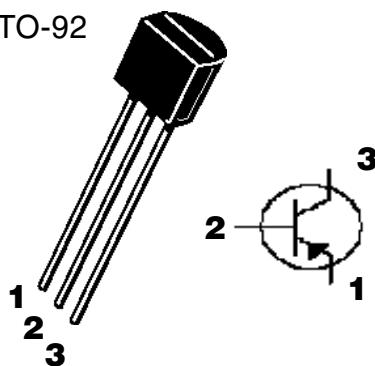
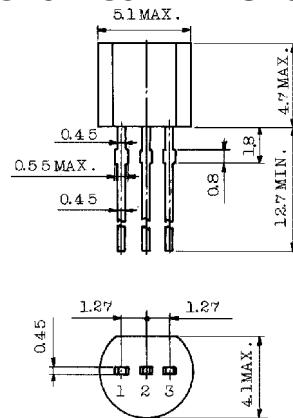


## Description

**TO-92**


## PNP General Purpose Transistors

## Mechanical Dimensions



### Maximum Ratings

Ratings	Symbol	Value	Units
Collector - Emitter Voltage	$V_{CEO}$	40	Vdc
Collector - Base Voltage	$V_{CBO}$	40	Vdc
Emitter - Base Voltage	$V_{EBO}$	5.0	Vdc
Collector Current (Continuous)	$I_C$	200	mAdc

### Thermal Characteristics

Characteristic	Symbol	Max	Units
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_A = 60^\circ\text{C}$	$P_D$	250	mW
Total Device Dissipation @ $T_c = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.5 12	Watts mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{QJA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{QJA}$	83.3	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	$^\circ\text{C}$

### Electrical Characteristics @ $25^\circ\text{C}$

Off Characteristic	Symbol	Min	Max	Unit
Collector - Emitter Breakdown Voltage (Note 1) ( $I_C = 1.0\text{mAdc}, I_B = 0$ )	$V_{BR(CEO)}$	40	---	Vdc
Collector - Base Breakdown Voltage ( $I_C = -10\mu\text{Aadc}, I_E = 0$ )	$V_{BR(CBO)}$	40	---	Vdc
Emitter - Base Breakdown Voltage ( $I_E = -10\mu\text{Aadc}, I_C = 0$ )	$V_{BR(EBO)}$	5.0	---	Vdc
Base Cutoff Current ( $V_{CE} = 30\text{Vdc}, V_{EB} = 3.0\text{Vdc}$ )	$I_{BL}$	---	50	nAdc
Collector Cutoff Current ( $V_{CE} = 30\text{Vdc}, V_{EB} = 3.0\text{Vdc}$ )	$I_{CEX}$	---	50	nAdc

Notes:

 (1) Pulse test: Pulse width  $\leq 300\ \mu\text{s}$ , duty cycle  $\leq 2.0\%$ .



## Electrical Characteristics @ 25°C

## On Characteristic

DC Current Gain  
 $(I_C = 0.1 \text{ mA DC}, V_{CE} = 1.0 \text{ V DC})$   
 2N3905  
 2N3906  
 $(I_C = 1.0 \text{ mA DC}, V_{CE} = 1.0 \text{ V DC})$   
 2N3905  
 2N3906  
 $(I_C = 10 \text{ mA DC}, V_{CE} = 1.0 \text{ V DC})$   
 2N3905  
 2N3906  
 $(I_C = 50 \text{ mA DC}, V_{CE} = 1.0 \text{ V DC})$   
 2N3905  
 2N3906  
 $(I_C = 100 \text{ mA DC}, V_{CE} = 1.0 \text{ V DC})$   
 2N3905  
 2N3906

Symbol	H <sub>FE</sub>	Min	Max	Unit
		30	---	---
		60	---	---
		40	---	---
		80	---	---
		50	150	
		100	300	
		30	---	---
		60	---	---
		15	---	---
		30	---	---

## Collector - Emitter Saturation Voltage (Note 1)

$(I_C = 10 \text{ mA DC}, I_B = 1.0 \text{ mA DC})$   
 $(I_C = 50 \text{ mA DC}, I_B = 5.0 \text{ mA DC})$

V <sub>CE(sat)</sub>	---	0.25	Vdc
	---	0.4	

## Base - Emitter Saturation Voltage (Note 1)

$(I_C = 10 \text{ mA DC}, I_B = 1.0 \text{ mA DC})$   
 $(I_C = 50 \text{ mA DC}, I_B = 5.0 \text{ mA DC})$

V <sub>BE(sat)</sub>	0.65	0.85	Vdc
	---	0.95	

## Small-Signal Characteristic

Current - Gain - Bandwidth Product  
 2N3905  
 $(I_C = -10 \text{ mA DC}, V_{CE} = -20 \text{ V DC}, f = 100 \text{ MHz})$  2N3906

f <sub>T</sub>	200	---	MHz
	250	---	

## Output Capacitance

$(V_{CB} = -5.0 \text{ V DC}, I_E = 0, f = 1.0 \text{ MHz})$

C <sub>obo</sub>	---	4.5	pF
	---	4.5	

## Input Capacitance

$(V_{EB} = -0.5 \text{ V DC}, I_C = 0, f = 1.0 \text{ MHz})$

C <sub>ibo</sub>	---	10	pF
	---	10	

## Input Impedance

2N3905  
 $(V_{CE} = -10 \text{ V DC}, I_C = -1.0 \text{ mA DC}, f = 1.0 \text{ kHz})$  2N3906

h <sub>ie</sub>	0.5	8.0	kΩ
	2.0	12	

## Voltage Feedback Ratio

2N3905  
 $(V_{CE} = -10 \text{ V DC}, I_C = -1.0 \text{ mA DC}, f = 1.0 \text{ kHz})$  2N3906

h <sub>re</sub>	0.1	5.0	x10 <sup>-4</sup>
	0.1	10	

## Small - Signal Current Gain

2N3905  
 $(V_{CE} = -10 \text{ V DC}, I_C = -1.0 \text{ mA DC}, f = 1.0 \text{ kHz})$  2N3906

h <sub>fe</sub>	50	200	---
	100	400	

## Output Admittance

2N3905  
 $(V_{CE} = -10 \text{ V DC}, I_C = -1.0 \text{ mA DC}, f = 1.0 \text{ kHz})$  2N3906

h <sub>oe</sub>	1.0	40	μmhos
	3.0	60	

Noise Figure (V<sub>CE</sub> = -5.0 V DC, I<sub>C</sub> = -100 μADC, R<sub>S</sub> = 1.0 kΩ, f = 1.0 kHz)

2N3905  
 2N3906

NF	---	5.0	dB
	---	4.0	

## Switching Characteristic

## Delay Time

$(V_{CC} = -3.0 \text{ V DC}, V_{BE} = 0.5 \text{ V DC},$   
 $I_C = -10 \text{ mA DC}, I_{B1} = -1.0 \text{ mA DC})$

t <sub>d</sub>	---	35	ns
	---	35	

## Rise Time

$I_C = -10 \text{ mA DC}, I_{B1} = -1.0 \text{ mA DC}$

t <sub>r</sub>	---	35	ns
	---	35	

## Storage Time

2N3905  
 $(V_{CC} = -3.0 \text{ V DC}, I_C = -10 \text{ mA DC},$   
 $I_{B1} = -1.0 \text{ mA DC})$  2N3906

t <sub>s</sub>	---	200	ns
	---	225	

## Fall Time

2N3905  
 $I_{B1} = I_{B2} = -1.0 \text{ mA DC}$  2N3906

t <sub>f</sub>	---	60	ns
	---	75	